

# PMDPB85UPE 20 V dual P-channel Trench MOSFET Rev. 1 — 20 June 2012

Product data sheet

### 1. **Product profile**

# 1.1 General description

Dual small-signal P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020-6 (SOT1118) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

# 1.2 Features and benefits

- Low threshold voltage
- Very fast switching

- Trench MOSFET technology
- 2 kV ElectroStatic Discharge (ESD) protection

# 1.3 Applications

- Relay driver
- High-speed line driver

- High-side load switch
- Switching circuits

# 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage			-8	-	8	V
I <sub>D</sub>	drain current	$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$	<u>[1]</u>	-	-	-3.7	Α
Static charact	Static characteristics (per transistor)						
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = -4.5 \text{ V}; I_D = -1.3 \text{ A}; T_j = 25 \text{ °C}$		-	82	103	mΩ

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



# 20 V dual P-channel Trench MOSFET

# **Pinning information**

Table 2. **Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1		D4 D0
2	G1	gate TR1	6 5 4	D1 D2
3	D2	drain TR2		
4	S2	source TR2	7   8	G1 $G2$ $G2$
5	G2	gate TR2		
6	D1	drain TR1	1 2 3	17
7	D1	drain TR1	Transparent top view	S1 S2 017aaa260
8	D2	drain TR2	DFN2020-6 (SOT1118)	

### **Ordering information** 3.

Table 3. **Ordering information** 

Type number	Package		
	Name	Description	Version
PMDPB85UPE	DFN2020-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1118

# **Marking**

Table 4. **Marking codes** 

Type number	Marking code
PMDPB85UPE	2C

# **Limiting values**

Table 5. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

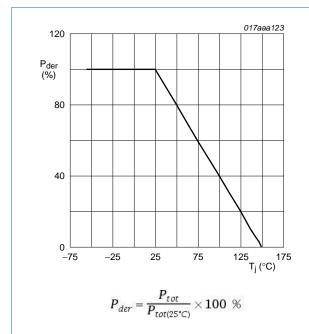
Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	tor					
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
$V_{GS}$	gate-source voltage			-8	8	V
$I_D$	drain current	$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$	<u>[1]</u>	-	-3.7	Α
		$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 \text{ °C}$	<u>[1]</u>	-	-2.9	Α
		$V_{GS} = -4.5 \text{ V}; T_{amb} = 100 ^{\circ}\text{C}$	<u>[1]</u>	-	-1.8	Α
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-11.6	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	515	mW
			<u>[1]</u>	-	1170	mW
		T <sub>sp</sub> = 25 °C		-	8330	mW
Source-dra	in diode					
Is	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1.2	Α
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Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
ESD maximum	n rating					
V <sub>ESD</sub>	electrostatic discharge voltage	HBM; C = 100 pF; R = 1.5 kΩ	[3]	-	2000	V
Per device						
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.
- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- Measured between all pins.



Normalized total power dissipation as a Fig 1. function of junction temperature

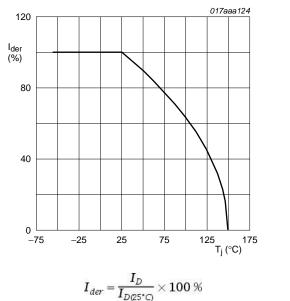


Fig 2. Normalized continuous drain current as a function of junction temperature

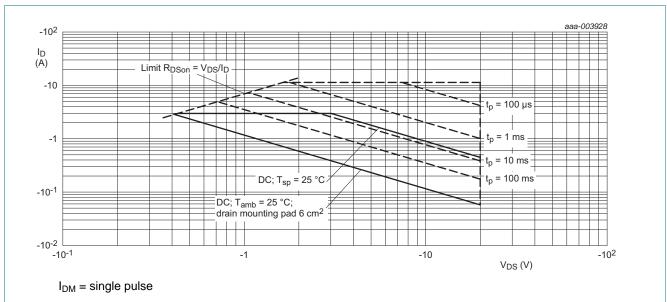


Fig 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

# 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
$R_{th(j-a)}$	thermal resistance		<u>[1]</u>	-	211	243	K/W
	from junction to ambient		[2]	-	93	107	K/W
	ambient	in free air; t ≤ 5 s	[2]	-	55	64	K/W
$R_{th(j\text{-sp})}$	thermal resistance from junction to solder point			-	12	15	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

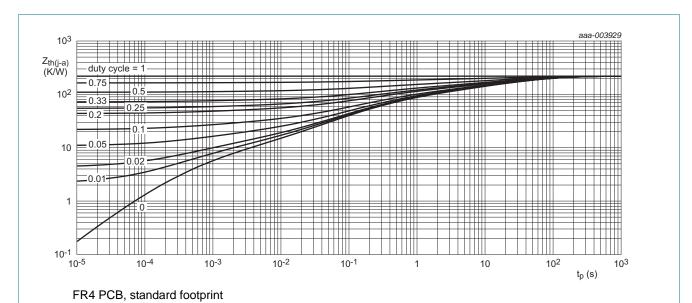


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

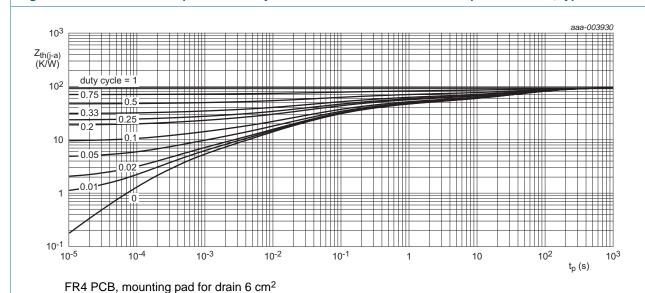


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

# 7. Characteristics

Table 7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics (per transistor)					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	-20	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-0.45	-0.7	-0.95	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-1	μΑ
		$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	-10	μΑ
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	10	μΑ
		$V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-10	μΑ
R <sub>DSon</sub>	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -1.3 \text{ A}; T_j = 25 \text{ °C}$	-	82	103	mΩ
	resistance	$V_{GS} = -4.5 \text{ V}; I_D = -1.3 \text{ A}; T_j = 150 \text{ °C}$	-	114	144	$m\Omega$
		$V_{GS} = -2.5 \text{ V}; I_D = -1.1 \text{ A}; T_j = 25 \text{ °C}$	-	107	146	mΩ
		$V_{GS} = -1.8 \text{ V}; I_D = -0.8 \text{ A}; T_j = 25 \text{ °C}$	-	142	210	mΩ
9 <sub>fs</sub>	forward transconductance	$V_{DS} = -10 \text{ V}; I_{D} = -1.3 \text{ A}; T_{j} = 25 \text{ °C}$	-	6	-	S
Dynamic	characteristics (per transist	or)				
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = -10 V; I <sub>D</sub> = -1.3 A; V <sub>GS</sub> = -4.5 V;	-	5.4	8.1	nC
$Q_{GS}$	gate-source charge	T <sub>j</sub> = 25 °C	-	0.7	-	nC
$Q_{GD}$	gate-drain charge		-	1	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS} = -10 \text{ V; } f = 1 \text{ MHz; } V_{GS} = 0 \text{ V;}$	-	514	-	pF
C <sub>oss</sub>	output capacitance	$T_j = 25  ^{\circ}C$	-	78	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	59	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = -10 \text{ V}; I_D = -1.3 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	6	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	12	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	47	-	ns
t <sub>f</sub>	fall time		-	21	-	ns
Source-d	rain diode (per transistor)					
$V_{SD}$	source-drain voltage	$I_S = -0.3 \text{ A}$ ; $V_{GS} = 0 \text{ V}$ ; $T_i = 25 \text{ °C}$	-	-0.7	-1.2	V

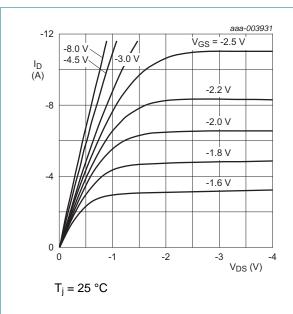


Fig 6. Output characteristics: drain current as a function of drain-source voltage; typical values

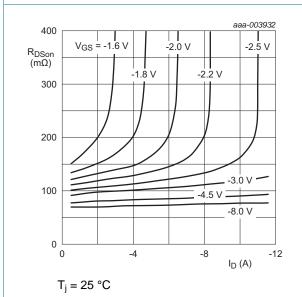
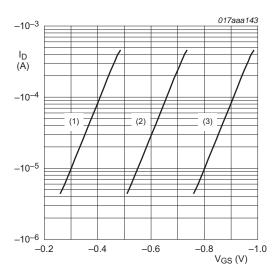


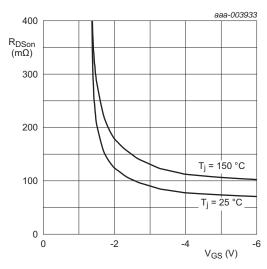
Fig 8. Drain-source on-state resistance as a function of drain current; typical values



 $T_{j} = 25 \, ^{\circ}\text{C}; \, V_{DS} = -3 \, \text{V}$ 

- (1) minimum values
- (2) typical values
- (3) maximum values

Fig 7. Sub-threshold drain current as a function of gate-source voltage



 $I_D = -1.3 A$ 

Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

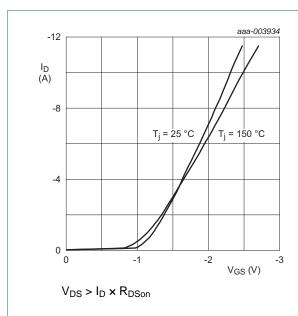


Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

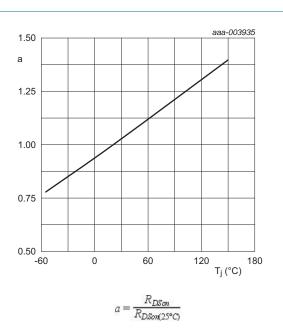


Fig 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

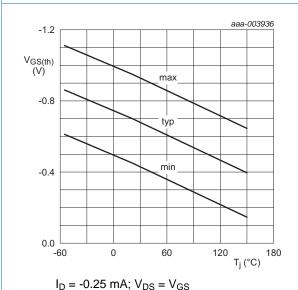


Fig 12. Gate-source threshold voltage as a function of

junction temperature

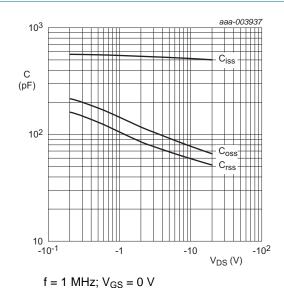
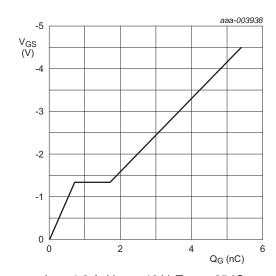


Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



 $I_D$  = -1.3 A;  $V_{DS}$  = -10 V;  $T_{amb}$  = 25 °C

Fig 14. Gate-source voltage as a function of gate charge; typical values

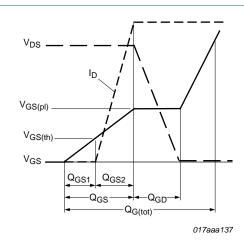
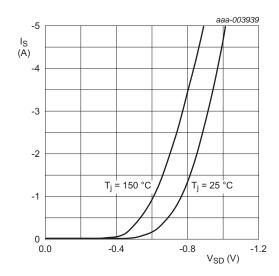


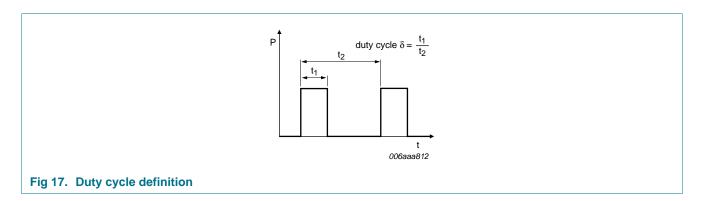
Fig 15. Gate charge waveform definitions



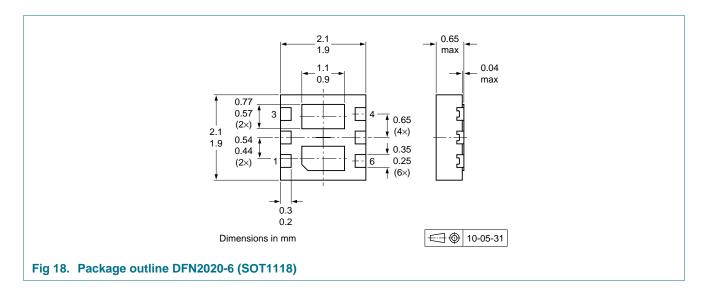
 $V_{GS} = 0 V$ 

Fig 16. Source current as a function of source-drain voltage; typical values

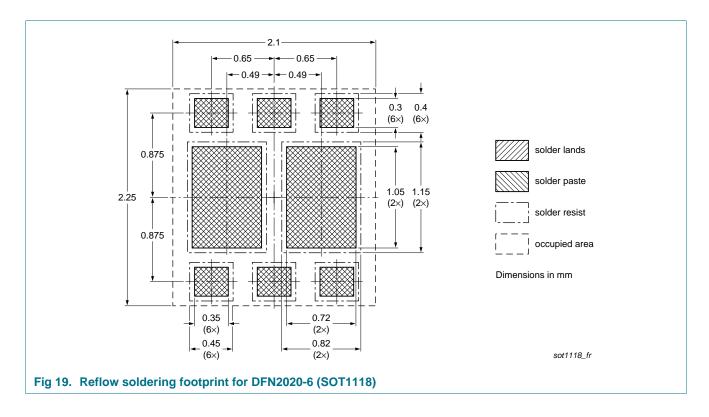
# 8. Test information



# 9. Package outline



# 10. Soldering





# 11. Revision history

# Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMDPB85UPE v.1	20120620	Product data sheet	-	-

# 12. Legal information

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Document status[1] [2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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# PMDPB85UPE

# 20 V dual P-channel Trench MOSFET

# 14. Contents

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